

1 μ A Low Dropout Positive Voltage Regulator

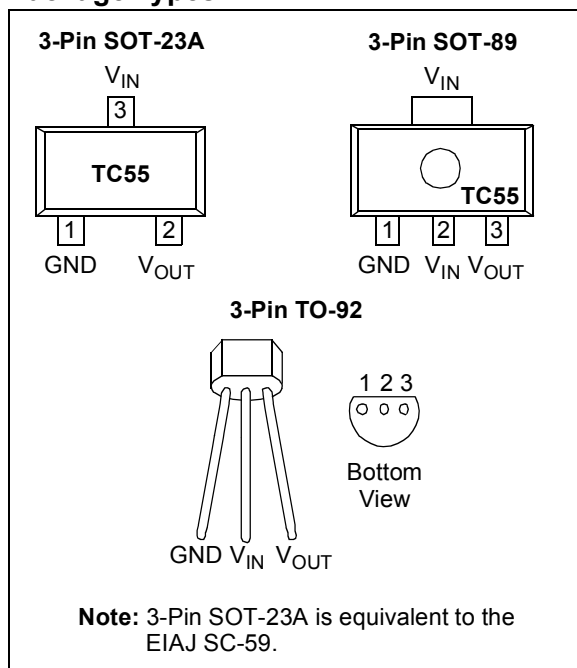
Features

- Low Dropout Voltage: 120 mV (typ) at 100 mA, 380 mV (typ) at 200 mA
- High Output Current: 250 mA ($V_{OUT} = 5.0V$)
- High Accuracy Output Voltage: $\pm 2\%$ (max) ($\pm 1\%$ Semi-Custom Version)
- Low Power Consumption: 1.1 μ A (typ)
- Low Temperature Drift: ± 100 ppm/ $^{\circ}C$ (typ)
- Excellent Line Regulation: 0.2%/V (typ)
- Package Options: 3-Pin SOT-23A, 3-Pin SOT-89 and 3-Pin TO-92
- Short-Circuit Protection
- Standard Output Voltage Options: 1.2V, 1.8V, 2.5V, 3.0V, 3.3V, 5.0V

Applications

- Battery-Powered Devices
- Cameras and Portable Video Equipment
- Pagers and Cellular Phones
- Solar Powered Instruments
- Consumer Products

Package Types



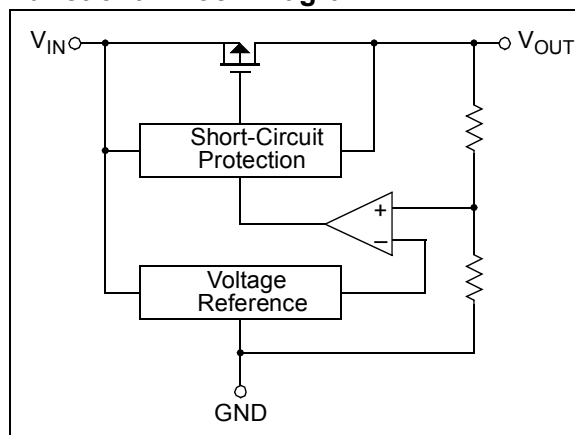
General Description

The TC55 Series is a collection of CMOS low dropout, positive voltage regulators that can source up to 250 mA of current, with an extremely low input-output voltage differential of 380 mV (typ) at 200 mA.

The TC55's low dropout voltage, combined with the low current consumption of only 1.1 μ A (typ), makes it ideal for battery operation. The low voltage differential (dropout voltage) extends the battery operating lifetime. It also permits high currents in small packages when operated with minimum $V_{IN} - V_{OUT}$ differentials.

The circuit also incorporates short-circuit protection to ensure maximum reliability.

Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

Input Voltage	+12V
Output Current (Continuous)	$P_D/(V_{IN} - V_{OUT})$ mA
Output Current (peak)	500 mA
Output Voltage	$(V_{SS} - 0.3V)$ to $(V_{IN} + 0.3V)$
Continuous Power Dissipation:	
3-Pin SOT-23A	240 mW
3-Pin SOT-89	500 mW
3-Pin TO-92	440 mW

† Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

PIN FUNCTION TABLE

Symbol	Description
GND	Ground Terminal
V_{OUT}	Regulated Voltage Output
V_{IN}	Unregulated Supply Input

TC55RP50: ELECTRICAL CHARACTERISTICS

Electrical Specifications: Unless otherwise specified, $V_{OUT}(S) = 5.0V$, $T_A = +25^\circ C$ (see Note 1).						
Parameters	Sym	Min	Typ	Max	Units	Conditions
Output Voltage	$V_{OUT}(A)$	— 4.90	— 5.0	— 5.10	V	$I_{OUT} = 40$ mA $V_{IN} = 6.0V$
Maximum Output Current	I_{OUTMAX}	250	—	—	mA	$V_{IN} = 6.0V$, $V_{OUT}(A) \geq 4.5V$
Load Regulation	ΔV_{OUT}	—	40	80	mV	$V_{IN} = 6.0V$, 1 mA $\leq I_{OUT} \leq 100$ mA
I/O Voltage Difference	V_{DIF}	— —	120 380	300 600	mV	$I_{OUT} = 100$ mA $I_{OUT} = 200$ mA
Current Consumption	I_{SS}	—	1.1	3.0	μA	$V_{IN} = 6.0V$
Voltage Regulation	$\frac{V_{OUT}(A) \cdot 100}{\Delta V_{IN} \cdot V_{OUT}(S)}$	—	0.2	0.3	%/V	$I_{OUT} = 40$ mA, $6.0V \leq V_{IN} \leq 10.0V$
Input Voltage	V_{IN}	—	—	10	V	
Temperature Coefficient of Output Voltage	$\frac{\Delta V_{OUT}(A) \cdot 10^6}{V_{OUT}(S) \cdot \Delta T_A}$	—	± 100	—	ppm/ $^\circ C$	$I_{OUT} = 40$ mA, $-40^\circ C \leq T_A \leq +85^\circ C$
Long-Term Stability		—	0.5	—	%	$T_A = +125^\circ C$, 1000 Hours

Note 1: $V_{OUT}(S)$: Preset value of output voltage; $V_{OUT}(A)$: Actual value of output voltage; V_{DIF} : Definition of I/O voltage difference = $\{V_{IN1} - V_{OUT}(A)\}$; $V_{OUT}(A)$: Output voltage when I_{OUT} is fixed and $V_{IN} = V_{OUT}(S) + 1.0V$; V_{IN1} : Input voltage when the output voltage is 98% $V_{OUT}(A)$.

TC55RP40: ELECTRICAL CHARACTERISTICS

Electrical Specifications: Unless otherwise specified, $V_{OUT}(S) = 4.0V$, $T_A = +25^\circ C$ (see Note 1).						
Parameters	Sym	Min	Typ	Max	Units	Conditions
Output Voltage	$V_{OUT}(A)$	— 3.92	— 4.0	— 4.08	V	$I_{OUT} = 40$ mA $V_{IN} = 5.0V$
Maximum Output Current	I_{OUTMAX}	200	—	—	mA	$V_{IN} = 5.0V$, $V_{OUT}(A) \geq 3.6V$
Load Regulation	ΔV_{OUT}	—	45	90	mV	$V_{IN} = 5.0V$, 1 mA $\leq I_{OUT} \leq 100$ mA
I/O Voltage Difference	V_{DIF}	— —	170 400	330 630	mV	$I_{OUT} = 100$ mA $I_{OUT} = 200$ mA
Current Consumption	I_{SS}	—	1.0	2.9	μA	$V_{IN} = 5.0V$
Voltage Regulation	$\frac{V_{OUT}(A) \cdot 100}{\Delta V_{IN} \cdot V_{OUT}(S)}$	—	0.2	0.3	%/V	$I_{OUT} = 40$ mA, $5.0V \leq V_{IN} \leq 10.0V$
Input Voltage	V_{IN}	—	—	10	V	
Temperature Coefficient of Output Voltage	$\frac{\Delta V_{OUT}(A) \cdot 10^6}{V_{OUT}(S) \cdot \Delta T_A}$	—	± 100	—	ppm/ $^\circ C$	$I_{OUT} = 40$ mA, $-40^\circ C \leq T_A \leq +85^\circ C$
Long-Term Stability		—	0.5	—	%	$T_A = +125^\circ C$, 1000 Hours

Note 1: $V_{OUT}(S)$: Preset value of output voltage; $V_{OUT}(A)$: Actual value of output voltage; V_{DIF} : Definition of I/O voltage difference = $\{V_{IN1} - V_{OUT}(A)\}$; $V_{OUT}(A)$: Output voltage when I_{OUT} is fixed and $V_{IN} = V_{OUT}(S) + 1.0V$; V_{IN1} : Input voltage when the output voltage is 98% $V_{OUT}(A)$.

TC55RP33: ELECTRICAL CHARACTERISTICS

Electrical Specifications: Unless otherwise specified, $V_{OUT}(S) = 3.3V$, $T_A = +25^{\circ}C$ (see **Note 1**).

Parameters	Sym	Min	Typ	Max	Units	Conditions
Output Voltage	$V_{OUT}(A)$	— 3.23	— 3.30	— 3.37	V	$I_{OUT} = 40\text{ mA}$ $V_{IN} = 4.3V$
Maximum Output Current	I_{OUTMAX}	150	—	—	mA	$V_{IN} = 4.3V$, $V_{OUT}(A) \geq 3.0V$
Load Regulation	ΔV_{OUT}	—	45	90	mV	$V_{IN} = 4.3V$, $1\text{ mA} \leq I_{OUT} \leq 80\text{ mA}$
I/O Voltage Difference	V_{DIF}	— —	180 400	360 700	mV	$I_{OUT} = 80\text{ mA}$ $I_{OUT} = 160\text{ mA}$
Current Consumption	I_{SS}	—	1.0	2.9	μA	$V_{IN} = 4.3V$
Voltage Regulation	$\frac{V_{OUT}(A) \cdot 100}{\Delta V_{IN} \cdot V_{OUT}(S)}$	—	0.2	0.3	%/V	$I_{OUT} = 40\text{ mA}$, $4.3V \leq I_{OUT} \leq 10.0V$
Input Voltage	V_{IN}	—	—	10	V	
Temperature Coefficient of Output Voltage	$\frac{\Delta V_{OUT}(A) \cdot 10^6}{V_{OUT}(S) \cdot \Delta T_A}$	—	± 100	—	ppm/ $^{\circ}C$	$I_{OUT} = 40\text{ mA}$, $-40^{\circ}C \leq T_A \leq +85^{\circ}C$
Long-Term Stability		—	0.5	—	%	$T_A = +125^{\circ}C$, 1,000 Hours

Note 1: $V_{OUT}(S)$: Preset value of output voltage; $V_{OUT}(A)$: Actual value of output voltage; V_{DIF} : Definition of I/O voltage difference = $\{V_{IN1} - V_{OUT}(A)\}$; $V_{OUT}(A)$: Output voltage when I_{OUT} is fixed and $V_{IN} = V_{OUT}(S) + 1.0V$; V_{IN1} : Input voltage when the output voltage is 98% $V_{OUT}(A)$.

TC55RP30: ELECTRICAL CHARACTERISTICS

Electrical Specifications: Unless otherwise specified, $V_{OUT}(S) = 3.0V$, $T_A = +25^{\circ}C$ (see **Note 1**).

Parameters	Sym	Min	Typ	Max	Units	Conditions
Output Voltage	$V_{OUT}(A)$	— 2.94	— 3.0	— 3.06	V	$I_{OUT} = 40\text{ mA}$ $V_{IN} = 4.0V$
Maximum Output Current	I_{OUTMAX}	150	—	—	mA	$V_{IN} = 4.0V$, $V_{OUT}(A) \geq 2.7V$
Load Regulation	ΔV_{OUT}	—	45	90	mV	$V_{IN} = 4.0V$, $1\text{ mA} \leq I_{OUT} \leq 80\text{ mA}$
I/O Voltage Difference	V_{DIF}	— —	180 400	360 700	mV	$I_{OUT} = 80\text{ mA}$ $I_{OUT} = 160\text{ mA}$
Current Consumption	I_{SS}	—	0.9	2.8	μA	$V_{IN} = 4.0V$
Voltage Regulation	$\frac{V_{OUT}(A) \cdot 100}{\Delta V_{IN} \cdot V_{OUT}(S)}$	—	0.2	0.3	%/V	$I_{OUT} = 40\text{ mA}$, $4.0V \leq V_{IN} \leq 10.0V$
Input Voltage	V_{IN}	—	—	10	V	
Temperature Coefficient of Output Voltage	$\frac{\Delta V_{OUT}(A) \cdot 10^6}{V_{OUT}(S) \cdot \Delta T_A}$	—	± 100	—	ppm/ $^{\circ}C$	$I_{OUT} = 40\text{ mA}$, $-40^{\circ}C \leq T_A \leq +85^{\circ}C$
Long-Term Stability		—	0.5	—	%	$T_A = +125^{\circ}C$, 1000 Hours

Note 1: $V_{OUT}(S)$: Preset value of output voltage; $V_{OUT}(A)$: Actual value of output voltage; V_{DIF} : Definition of I/O voltage difference = $\{V_{IN1} - V_{OUT}(A)\}$; $V_{OUT}(A)$: Output voltage when I_{OUT} is fixed and $V_{IN} = V_{OUT}(S) + 1.0V$; V_{IN1} : Input voltage when the output voltage is 98% $V_{OUT}(A)$.

TC55RP25: ELECTRICAL CHARACTERISTICS

Electrical Specifications: Unless otherwise specified, $V_{OUT}(S) = 2.5V$, $T_A = +25^{\circ}C$ (see Note 1).						
Parameters	Sym	Min	Typ	Max	Units	Conditions
Output Voltage	$V_{OUT}(A)$	— 2.45	— 2.5	— 2.55	V	$I_{OUT} = 40\text{ mA}$ $V_{IN} = 3.5V$
Maximum Output Current	I_{OUTMAX}	125	—	—	mA	$V_{IN} = 3.5V$, $V_{OUT}(A) \geq 2.25V$
Load Regulation	ΔV_{OUT}	—	45	90	mV	$V_{IN} = 3.5V$, $1\text{ mA} \leq I_{OUT} \leq 60\text{ mA}$
I/O Voltage Difference	V_{DIF}	—	180 400	360 700	mV	$I_{OUT} = 60\text{ mA}$ $I_{OUT} = 120\text{ mA}$
Current Consumption	I_{SS}	—	1.0	2.8	μA	$V_{IN} = 3.5V$
Voltage Regulation	$\frac{V_{OUT}(A) \cdot 100}{\Delta V_{IN} \cdot V_{OUT}(S)}$	—	0.2	0.3	%/V	$I_{OUT} = 40\text{ mA}$, $3.5V \leq I_{OUT} \leq 10.0V$
Input Voltage	V_{IN}	—	—	10	V	
Temperature Coefficient of Output Voltage	$\frac{\Delta V_{OUT}(A) \cdot 10^6}{V_{OUT}(S) \cdot \Delta T_A}$	—	± 100	—	ppm/ $^{\circ}C$	$I_{OUT} = 40\text{ mA}$, $-30^{\circ}C \leq T_A \leq +80^{\circ}C$
Long-Term Stability		—	0.5	—	%	$T_A = +125^{\circ}C$, 1,000 Hours

Note 1: $V_{OUT}(S)$: Preset value of output voltage; $V_{OUT}(A)$: Actual value of output voltage; V_{DIF} : Definition of I/O voltage difference = $\{V_{IN1} - V_{OUT}(A)\}$; $V_{OUT}(A)$: Output voltage when I_{OUT} is fixed and $V_{IN} = V_{OUT}(S) + 1.0V$; V_{IN1} : Input voltage when the output voltage is 98% $V_{OUT}(A)$.

TC55RP18: ELECTRICAL CHARACTERISTICS

Electrical Specifications: Unless otherwise specified, $V_{OUT}(S) = 1.8V$, $T_A = +25^{\circ}C$ (see Note 1).						
Parameters	Sym	Min	Typ	Max	Units	Conditions
Output Voltage	$V_{OUT}(A)$	— 1.764	— 1.8	— 1.836	V	$I_{OUT} = 0.5\text{ mA}$ $V_{IN} = 2.8V$
Maximum Output Current	I_{OUTMAX}	110	—	—	mA	$V_{IN} = 2.8V$, $V_{OUT}(A) \geq 1.62V$
Load Regulation	ΔV_{OUT}	—	—	30	mV	$V_{IN} = 2.8V$, $1\text{ mA} \leq I_{OUT} \leq 30\text{ mA}$
I/O Voltage Difference	V_{DIF}	—	—	300	mV	$I_{OUT} = 0.5\text{ mA}$
Current Consumption	I_{SS}	—	—	3.0	μA	$V_{IN} = 2.8V$
Voltage Regulation	$\frac{V_{OUT}(A) \cdot 100}{\Delta V_{IN} \cdot V_{OUT}(S)}$	—	—	0.25	%/V	$I_{OUT} = 0.5\text{ mA}$, $2.8V \leq I_{OUT} \leq 10.0V$
Input Voltage	V_{IN}	—	—	6.0	V	
Temperature Coefficient of Output Voltage	$\frac{\Delta V_{OUT}(A) \cdot 10^6}{V_{OUT}(S) \cdot \Delta T_A}$	—	± 100	—	ppm/ $^{\circ}C$	$I_{OUT} = 0.5\text{ mA}$, $-30^{\circ}C \leq T_A \leq +80^{\circ}C$
Long-Term Stability		—	0.5	—	%	$T_A = +125^{\circ}C$, 1,000 Hours

Note 1: $V_{OUT}(S)$: Preset value of output voltage; $V_{OUT}(A)$: Actual value of output voltage; V_{DIF} : Definition of I/O voltage difference = $\{V_{IN1} - V_{OUT}(A)\}$; $V_{OUT}(A)$: Output voltage when I_{OUT} is fixed and $V_{IN} = V_{OUT}(S) + 1.0V$; V_{IN1} : Input voltage when the output voltage is 98% $V_{OUT}(A)$.

TC55RP12: ELECTRICAL CHARACTERISTICS

Electrical Specifications: Unless otherwise specified, $V_{OUT}(S) = 1.2V$, $T_A = +25^{\circ}C$ (see Note 1).						
Parameters	Sym	Min	Typ	Max	Units	Conditions
Output Voltage	$V_{OUT}(A)$	— 1.176	— 1.200	— 1.224	V	$I_{OUT} = 0.5\text{ mA}$ $V_{IN} = 2.2V$
Maximum Output Current	I_{OUTMAX}	50	—	—	mA	$V_{IN} = 2.2V$, $V_{OUT}(A) \geq 1.08V$
Load Regulation	ΔV_{OUT}	—	—	30	mV	$V_{IN} = 2.2V$, $1\text{ mA} \leq I_{OUT} \leq 30\text{ mA}$
I/O Voltage Difference	V_{DIF}	—	—	300	mV	$I_{OUT} = 0.5\text{ mA}$
Current Consumption	I_{SS}	—	—	3.0	μA	$V_{IN} = 2.2V$
Voltage Regulation	$\frac{V_{OUT}(A) \cdot 100}{\Delta V_{IN} \cdot V_{OUT}(S)}$	—	—	0.25	%/V	$I_{OUT} = 0.5$, $2.2V \leq I_{OUT} \leq 10.0V$
Input Voltage	V_{IN}	—	—	6.0	V	
Temperature Coefficient of Output Voltage	$\frac{\Delta V_{OUT}(A) \cdot 10^6}{V_{OUT}(S) \cdot \Delta T_A}$	—	± 100	—	ppm/ $^{\circ}C$	$I_{OUT} = 0.5\text{ mA}$, $-30^{\circ}C \leq T_A \leq +80^{\circ}C$
Long-Term Stability		—	0.5	—	%	$T_A = +125^{\circ}C$, 1,000 Hours

Note 1: $V_{OUT}(S)$: Preset value of output voltage; $V_{OUT}(A)$: Actual value of output voltage; V_{DIF} : Definition of I/O voltage difference = $\{V_{IN1} - V_{OUT}(A)\}$; $V_{OUT}(A)$: Output voltage when I_{OUT} is fixed and $V_{IN} = V_{OUT}(S) + 1.0V$; V_{IN1} : Input voltage when the output voltage is 98% $V_{OUT}(A)$.

TEMPERATURE CHARACTERISTICS

Electrical Specifications: Unless otherwise specified, $V_{OUT}(S) = 5.0V$, $T_A = +25^{\circ}C$.						
Parameters	Sym	Min	Typ	Max	Units	Conditions
Temperature Ranges						
Specified Temperature Range (E)	T_A	-40	—	+85	$^{\circ}C$	
Storage Temperature Range	T_A	-65	—	+150	$^{\circ}C$	
Package Thermal Resistances						
Thermal Resistance, 3L-SOT-23A	θ_{JA}	—	359	—	$^{\circ}C/W$	
Thermal Resistance, 3L-SOT-89	θ_{JA}	—	110	—	$^{\circ}C/W$	When mounted on 1 square inch of copper
Thermal Resistance, 3L-TO-92	θ_{JA}	—	131.9	—	$^{\circ}C/W$	

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Notes: Unless otherwise specified, $V_{OUT}(S) = 3.0V, 5.0V$, $T_A = +25^\circ C$, $C_{IN} = 1 \mu F$ Tantalum, $C_{OUT} = 1 \mu F$ Tantalum.

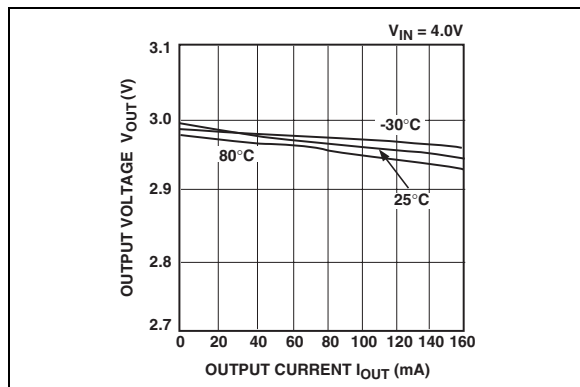


FIGURE 2-1: Output Voltage vs. Output Current (TC55RP3002).

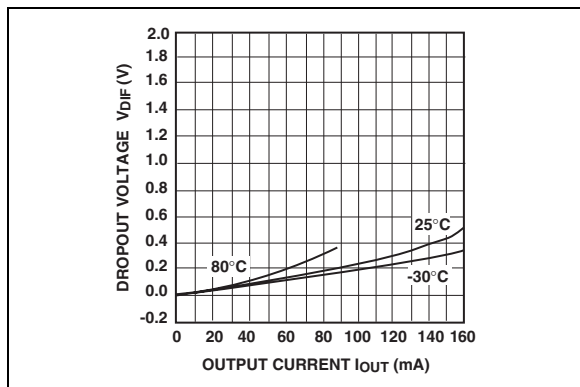


FIGURE 2-4: Dropout Voltage vs. Output Current (TC55RP3002).

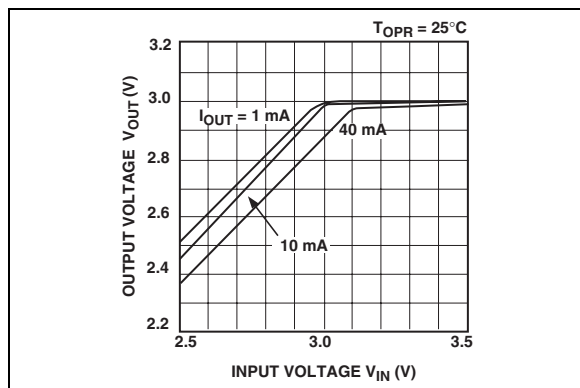


FIGURE 2-2: Output Voltage vs. Input Voltage (TC55RP3002).

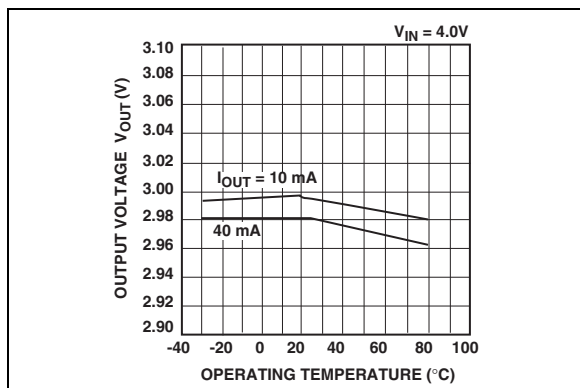


FIGURE 2-5: Output Voltage vs. Operating Temperature (TC55RP3002).

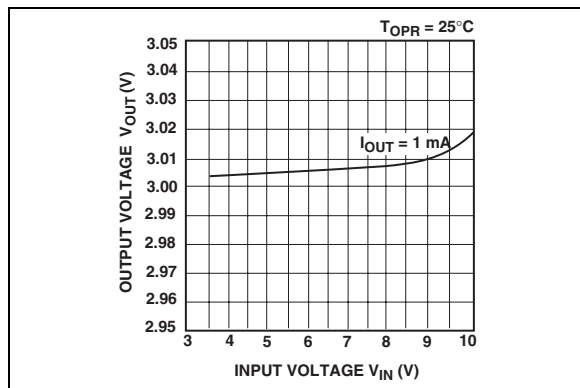


FIGURE 2-3: Output Voltage vs. Input Voltage (TC55RP3002).

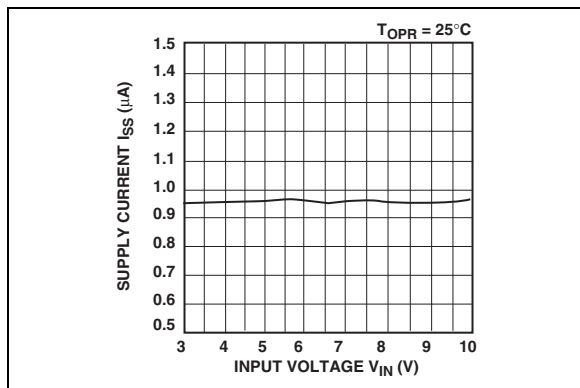


FIGURE 2-6: Supply Current vs. Input Voltage (TC55RP3002).

Note: Unless otherwise indicated, $V_{OUT}(S) = 3.0V, 5.0V$, $T_A = +25^\circ C$, $C_{IN} = 1 \mu F$ Tantalum, $C_{OUT} = 1 \mu F$ Tantalum.

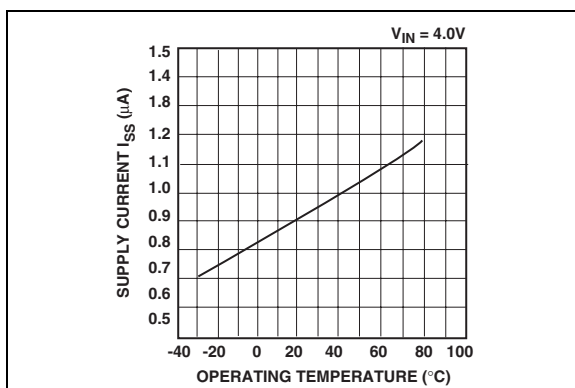


FIGURE 2-7: Supply Current vs. Operating Temperature (TC55RP3002).

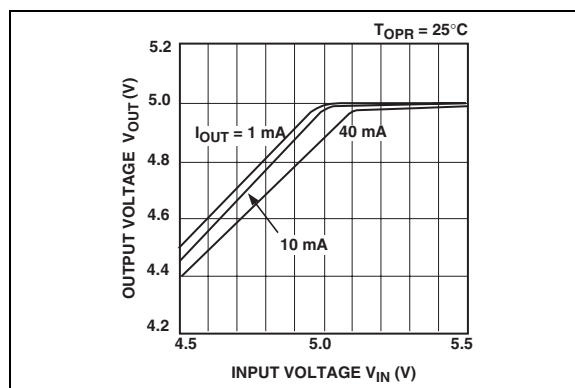


FIGURE 2-10: Output Voltage vs. Input Voltage (TC55RP5002).

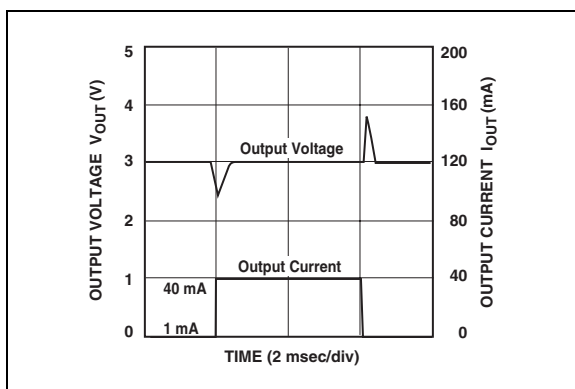


FIGURE 2-8: Load Transient Response (TC55RP3002).

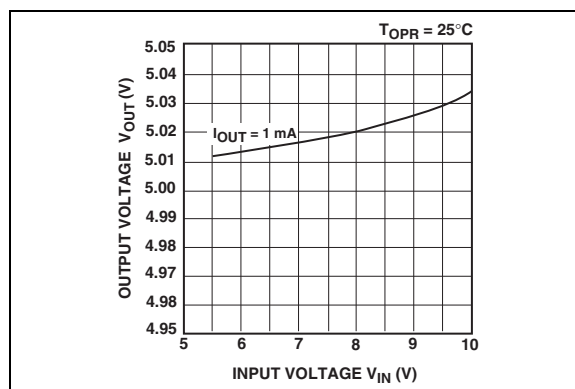


FIGURE 2-11: Output Voltage vs. Input Voltage (TC55RP5002).

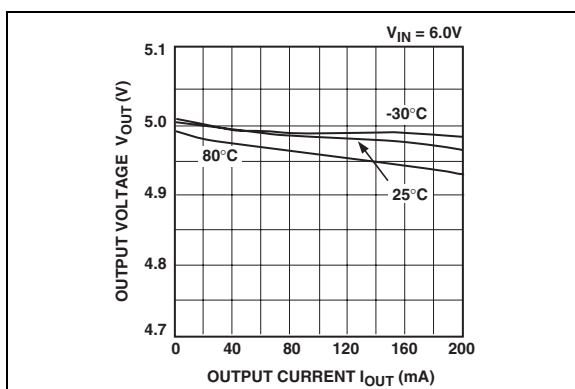


FIGURE 2-9: Output Voltage vs. Output Current (TC55RP5002).

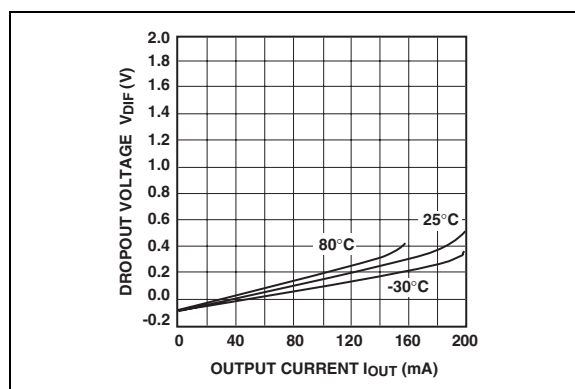


FIGURE 2-12: Dropout Voltage vs. Output Current (TC55RP5002).

Note: Unless otherwise indicated, $V_{OUT(S)} = 3.0V, 5.0V$, $T_A = +25^\circ C$, $C_{IN} = 1 \mu F$ Tantalum, $C_{OUT} = 1 \mu F$ Tantalum.

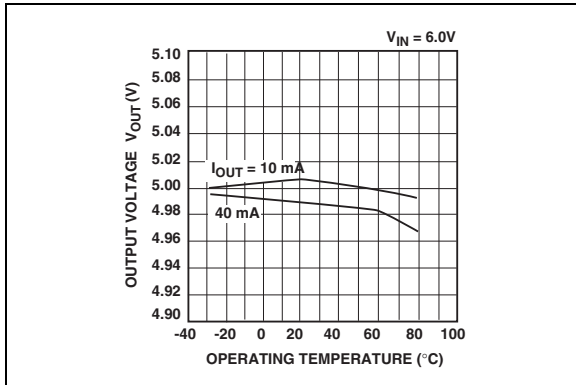


FIGURE 2-13: Output Voltage vs. Operating Temperature (TC55RP5002).

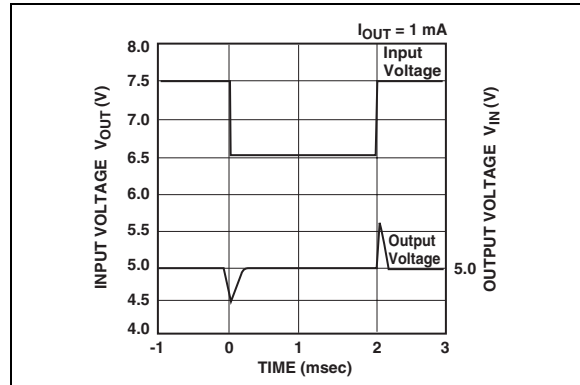


FIGURE 2-16: Input Transient Response, 1 mA (TC55RP5002).

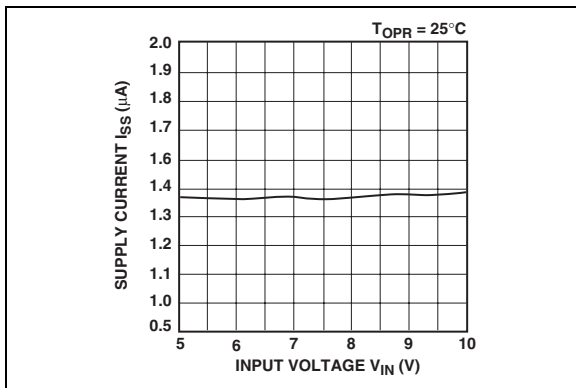


FIGURE 2-14: Supply Current vs. Input Voltage (TC55RP5002).

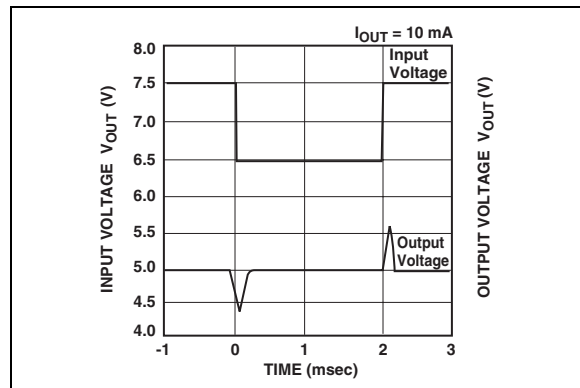


FIGURE 2-17: Input Transient Response, 10 mA (TC55RP5002).

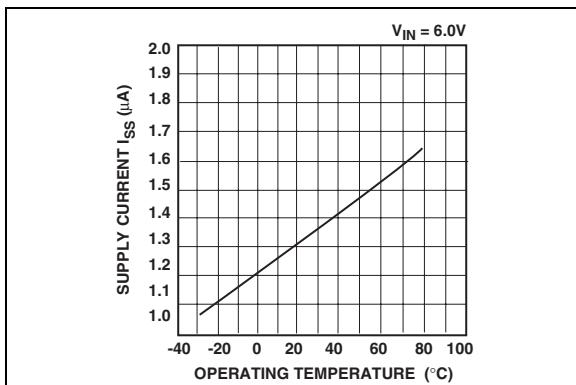


FIGURE 2-15: Supply Current vs. Operating Temperature (TC55RP5002).

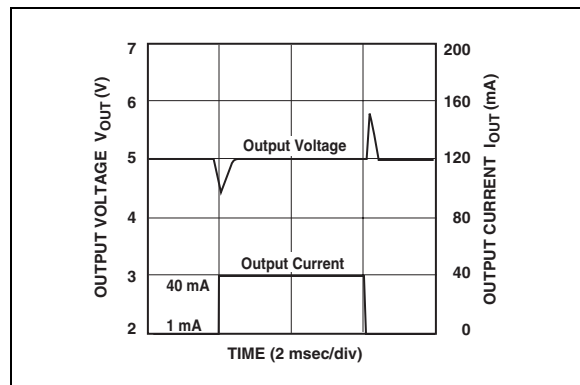


FIGURE 2-18: Load Transient Response (TC55RP5002).

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

Pin No.	Symbol	Description
1	GND	Ground Terminal
2	V _{OUT}	Regulated Voltage Output
3	V _{IN}	Unregulated Supply Input

3.1 Ground Terminal (GND)

Regulator ground. Tie GND to the negative side of the output and the negative side of the input capacitor. Only the LDO bias current (1 μ A typical) flows out of this pin, there is no high current. The LDO output regulation is referenced to this pin. Minimize voltage drops between this pin and the minus side of the load.

3.2 Regulated Voltage Output (V_{OUT})

Connect V_{OUT} to the positive side of the load and the positive terminal of the output capacitor. The positive side of the output capacitor should be physically located as close to the LDO V_{OUT} pin as is practical. The current flowing out of this pin is equal to the DC load current.

3.3 Unregulated Supply Input (V_{IN})

Connect the input supply voltage and the positive side of the input capacitor to V_{IN}. The input capacitor should be physically located as close as is practical to V_{IN}. The current flow into this pin is equal to the DC load current, plus the LDO bias current (1 μ A typical.)

4.0 DETAILED DESCRIPTION

The TC55 is a low quiescent current, precision, fixed-output voltage LDO. Unlike bipolar regulators, the TC55 supply current does not increase proportionally with load current.

4.1 Output Capacitor

A minimum of 1 μ F output capacitor is required. The output capacitor should have an effective series resistance (esr) greater than 0.1 Ω and less than 5 Ω , plus a resonant frequency above 1 MHz. Larger output capacitors can be used to improve supply noise rejection and transient response. Care should be taken when increasing C_{OUT} to ensure that the input impedance is not high enough to cause high input impedance oscillation.

4.2 Input Capacitor

A 1 μ F input capacitor is recommended for most applications when the input impedance is on the order of 10 Ω . Larger input capacitance may be required for stability when operating off of a battery input, or if there is a large distance from the input source to the LDO. When large values of output capacitance are used, the input capacitance should be increased to prevent high source impedance oscillations.

5.0 THERMAL CONSIDERATIONS

5.1 Power Dissipation

The amount of power dissipated internal to the low dropout linear regulator is the sum of the power dissipation within the linear pass device (P-Channel MOSFET) and the quiescent current required to bias the internal reference and error amplifier. The internal linear pass device power dissipation is calculated by multiplying the voltage across the linear device by the current through the device.

EQUATION

$$P_D (\text{Pass Device}) = (V_{IN} - V_{OUT}) \times I_{OUT}$$

The internal power dissipation, as a result of the bias current for the LDO internal reference and error amplifier, is calculated by multiplying the ground or quiescent current by the input voltage.

EQUATION

$$P_D (\text{Bias}) = V_{IN} \times I_{GND}$$

The total internal power dissipation is the sum of P_D (Pass Device) and P_D (Bias).

EQUATION

$$P_{TOTAL} = P_D (\text{Pass Device}) + P_D (\text{Bias})$$

For the TC55, the internal quiescent bias current is so low (1 μ A typical) that the P_D (Bias) term of the power dissipation equation can be ignored. The maximum power dissipation can be estimated by using the maximum input voltage and the minimum output voltage to obtain a maximum voltage differential between input and output. The next step would be to multiply the maximum voltage differential by the maximum output current.

EQUATION

$$P_D = (V_{INMAX} - V_{OUTMIN}) \times I_{OUTMAX}$$

Given:

$$V_{IN} = 3.3V \text{ to } 4.1V$$

$$V_{OUT} = 3.0V \pm 2\%$$

$$I_{OUT} = 1 \text{ mA to } 100 \text{ mA}$$

$$T_{AMAX} = 55^\circ\text{C}$$

$$P_{MAX} = (4.1V - (3.0V \times 0.98)) \times 100 \text{ mA}$$

$$P_{MAX} = 116.0 \text{ milliwatts}$$

To determine the junction temperature of the device, the thermal resistance from junction-to-ambient must be known. The 3-pin SOT-23 thermal resistance from junction-to-air ($R_{\theta JA}$) is estimated to be approximately 359°C/W. The SOT-89 $R_{\theta JA}$ is estimated to be approximately 110°C/W when mounted on 1 square inch of copper. The TO-92 $R_{\theta JA}$ is estimated to be 131.9°C/W. The $R_{\theta JA}$ will vary with physical layout, airflow and other application-specific conditions.

The device junction temperature is determined by calculating the junction temperature rise above ambient, then adding the rise to the ambient temperature.

EQUATION

Junction Temperature

SOT-23 Example:

$$T_J = P_{DMAX} \times R_{\theta JA} + T_A$$

$$T_J = 116.0 \text{ milliwatts} \times 359^\circ\text{C/W} + 55^\circ\text{C}$$

$$T_J = 96.6^\circ\text{C}$$

SOT-89 Example:

$$T_J = 116.0 \text{ milliwatts} \times 110^\circ\text{C/W} + 55^\circ\text{C}$$

$$T_J = 67.8^\circ\text{C}$$

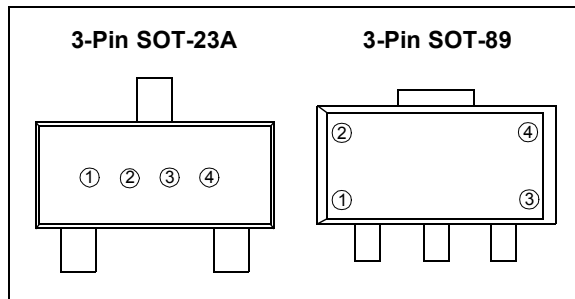
TO-92 Example:

$$T_J = 116.0 \text{ milliwatts} \times 131.9^\circ\text{C/W} + 55^\circ\text{C}$$

$$T_J = 70.3^\circ\text{C}$$

6.0 PACKAGING INFORMATION

6.1 Package Marking Information



① represents first voltage digit
2V, 3V, 4V, 5V, 6V

Ex: 3.xV = ③ ○ ○ ○

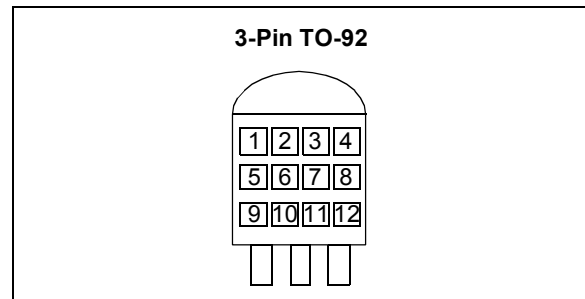
② represents first decimal place voltage (x.0 - x.9)

Ex: 3.4V = ③ ④ ○ ○

Symbol	Voltage	Symbol	Voltage
A	x.0	F	x.5
B	x.1	H	x.6
C	x.2	K	x.7
D	x.3	L	x.8
E	x.4	M	x.9

③ represents polarity
0 = Positive (fixed)

④ represents assembly lot number



①, ②, ③ & ④ = 55RP (fixed)

⑤ represents first voltage digit (2-6)

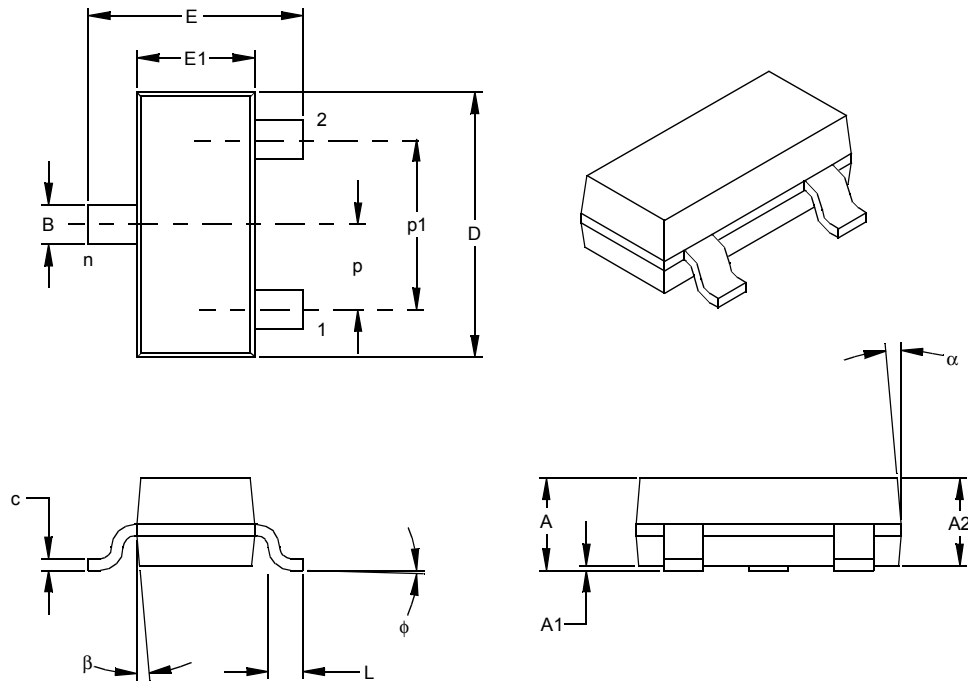
⑥ represents first voltage decimal (0-9)

⑦ represents extra feature code: fixed: 0

⑧ represents regulation accuracy
1 = $\pm 1.0\%$ (custom), 2 = $\pm 2.0\%$ (standard)

⑨, ⑩, ⑪ & ⑫ represents assembly lot number

3-Lead Plastic Small Outline Transistor (CB) (SOT23)



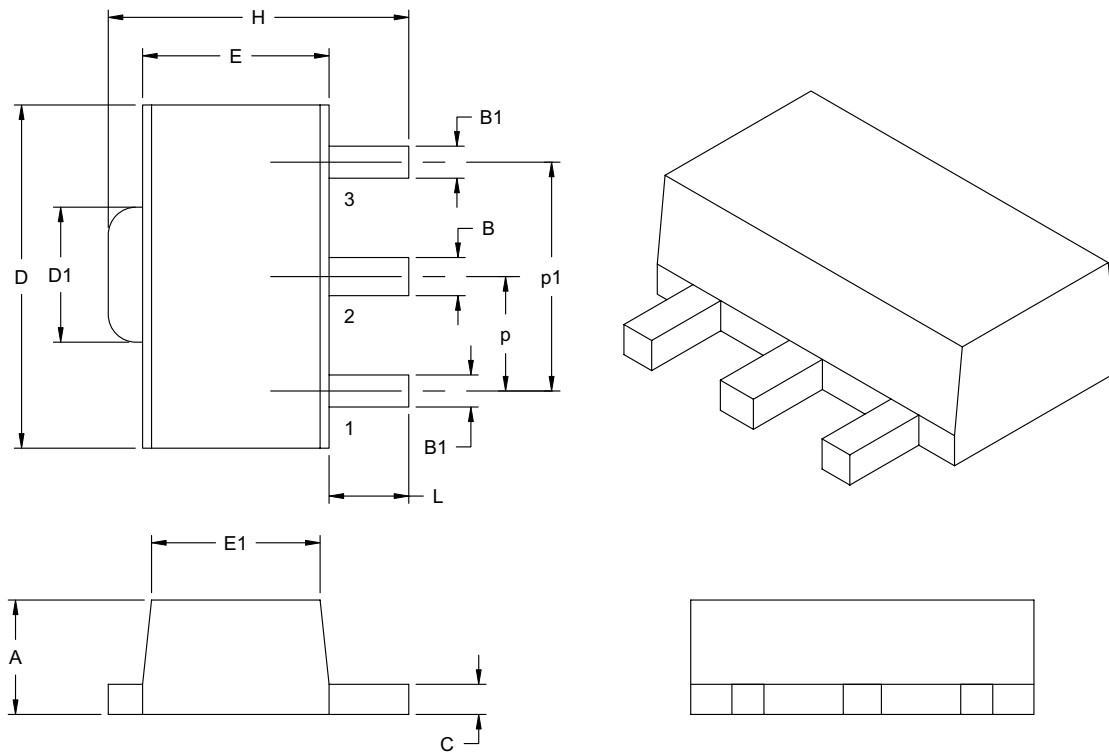
Units		INCHES*			MILLIMETERS		
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		3			3	
Pitch	p		.038			0.96	
Outside lead pitch (basic)	p1		.076			1.92	
Overall Height	A	.035	.040	.044	0.89	1.01	1.12
Molded Package Thickness	A2	.035	.037	.040	0.88	0.95	1.02
Standoff §	A1	.000	.002	.004	0.01	0.06	0.10
Overall Width	E	.083	.093	.104	2.10	2.37	2.64
Molded Package Width	E1	.047	.051	.055	1.20	1.30	1.40
Overall Length	D	.110	.115	.120	2.80	2.92	3.04
Foot Length	L	.014	.018	.022	0.35	0.45	0.55
Foot Angle	φ	0	5	10	0	5	10
Lead Thickness	c	.004	.006	.007	0.09	0.14	0.18
Lead Width	B	.015	.017	.020	0.37	0.44	0.51
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

* Controlling Parameter
§ Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.
JEDEC Equivalent: TO-236
Drawing No. C04-104

3-Lead Plastic Small Outline Transistor (MB) (SOT89)



Dimension Limits	Units	INCHES		MILLIMETERS*	
		MIN	MAX	MIN	MAX
Pitch	P	.059 BSC		1.50 BSC	
Outside lead pitch (basic)	p1	.118 BSC		3.00 BSC	
Overall Height	A	.055	.063	1.40	1.60
Overall Width	H	.155	.167	3.94	4.25
Molded Package Width at Base	E	.090	.102	2.29	2.60
Molded Package Width at Top	E1	.084	.090	2.13	2.29
Overall Length	D	.173	.181	4.40	4.60
Tab Length	D1	.064	.072	1.62	1.83
Foot Length	L	.035	.047	0.89	1.20
Lead Thickness	c	.014	.017	0.35	0.44
Lead 2 Width	B	.017	.022	0.44	0.56
Leads 1 & 3 Width	B1	.014	.019	0.36	0.48

*Controlling Parameter

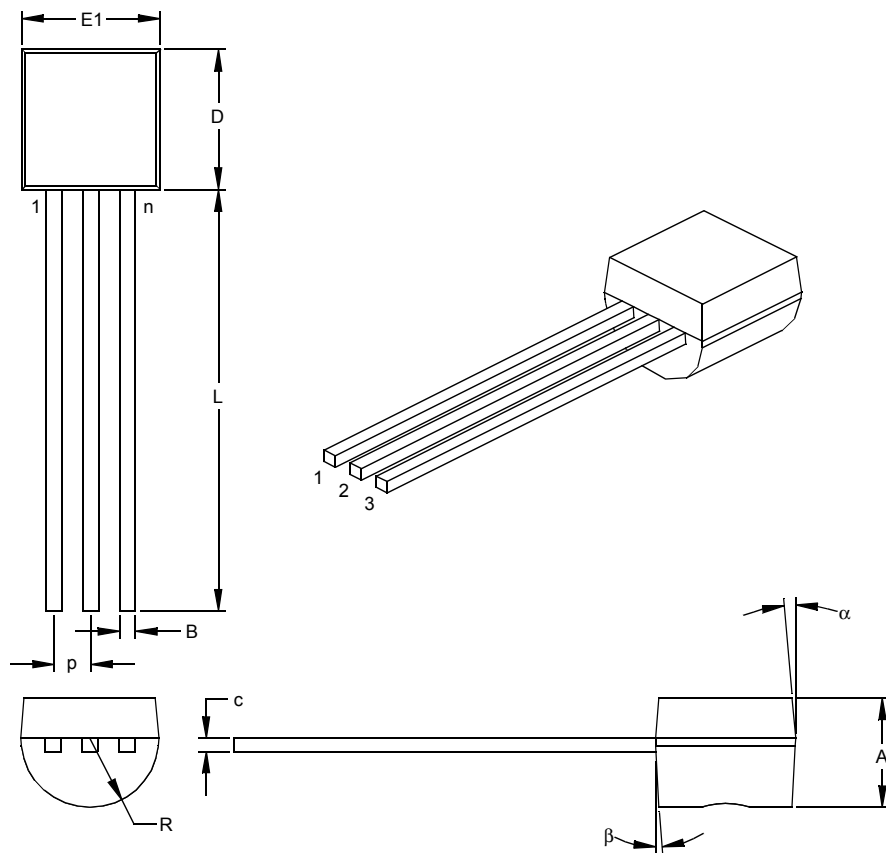
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

JEDEC Equivalent: TO-243

Drawing No. C04-29

3-Lead Plastic Transistor Outline (ZB) (TO-92)



Units		INCHES*			MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		3			3	
Pitch	p		.050			1.27	
Bottom to Package Flat	A	.130	.143	.155	3.30	3.62	3.94
Overall Width	E1	.175	.186	.195	4.45	4.71	4.95
Overall Length	D	.170	.183	.195	4.32	4.64	4.95
Molded Package Radius	R	.085	.090	.095	2.16	2.29	2.41
Tip to Seating Plane	L	.500	.555	.610	12.70	14.10	15.49
Lead Thickness	c	.014	.017	.020	0.36	0.43	0.51
Lead Width	B	.016	.019	.022	0.41	0.48	0.56
Mold Draft Angle Top	α	4	5	6	4	5	6
Mold Draft Angle Bottom	β	2	3	4	2	3	4

*Controlling Parameter

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side.

JEDEC Equivalent: TO-92

Drawing No. C04-101

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>PART NO.</u>	<u>XX</u>	<u>X</u>	<u>X</u>	<u>X</u>	<u>XX</u>	<u>XX</u>
Device	Output Voltage	Feature Code	Tolerance	Temp.	Package	Taping Direction
Device: TC55: 1 μA Low Dropout Positive Voltage Regulator Output Voltage: 12 = 1.2V "Standard" 18 = 1.8V "Standard" 25 = 2.5V "Standard" 30 = 3.0V "Standard" 33 = 3.3V "Standard" 50 = 5.0V "Standard" Extra Feature Code: 0 = Fixed Tolerance: 1 = 1.0% (Custom) 2 = 2.0% (Standard) Temperature: E = -40°C to +85°C Package Type: CB = 3-Pin SOT-23A (equivalent to EIAJ SC-59) MB = 3-Pin SOT-89 ZB = 3-Pin TO-92 Taping Direction: TR = Standard 713 = Standard						
Examples: a) TC55RP1802ECB713: 1.8V LDO Positive Voltage Regulator, 2% Tolerance SOT23-A-3 package. b) TC55RP2502EMB713: 1.8V LDO Positive Voltage Regulator, 2% Tolerance. SOT89-3 package. c) TC55RP2502ECB713: 2.5V LDO Positive Voltage Regulator, 2% Tolerance. SOT23-A-3 package. d) TC55RP3002ECB713: 3.0V LDO Positive Voltage Regulator, 2% Tolerance. SOT23-A-3 package. e) TC55RP3002EMB713: 3.0V LDO Positive Voltage Regulator, 2% Tolerance. SOT89-3 package. f) TC55RP3302ECB713: 3.3V LDO Positive Voltage Regulator, 2% Tolerance. SOT23-A-3 package. g) TC55RP3302EMB713: 3.3V LDO Positive Voltage Regulator, 2% Tolerance. SOT89-3 package. h) TC55RP5002ECB713: 5.0V LDO Positive Voltage Regulator, 2% Tolerance. SOT23-A-3 package. i) TC55RP5002EMB713: 5.0V LDO Positive Voltage Regulator, 2% Tolerance. SOT89-3 package.						

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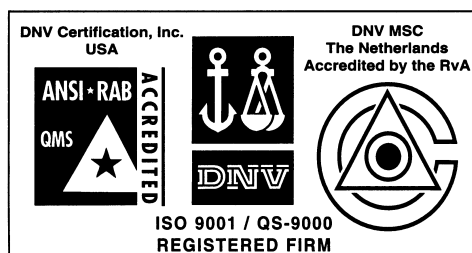
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San Jose, CA 95131
Tel: 408-436-7950 Fax: 408-436-7955

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6285 Northam Drive, Suite 108
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Tel: 905-673-0699 Fax: 905-673-6509

ASIA/PACIFIC

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Marketing Support Division
Suite 22, 41 Rawson Street
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Australia
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Microchip Technology Consulting (Shanghai)
Co., Ltd., Beijing Liaison Office
Unit 915
Bei Hai Wan Tai Bldg.
No. 6 Chaoyangmen Beidajie
Beijing, 100027, No. China
Tel: 86-10-85282100 Fax: 86-10-85282104

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Co., Ltd., Chengdu Liaison Office
Rm. 2401-2402, 24th Floor,
Ming Xing Financial Tower
No. 88 TIDU Street
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Tel: 86-28-86766200 Fax: 86-28-86766599

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Tel: 86-591-7503506 Fax: 86-591-7503521

China - Hong Kong SAR

Microchip Technology Hongkong Ltd.
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Tel: 852-2401-1200 Fax: 852-2401-3431

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Far East International Plaza
No. 317 Xian Xia Road
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Microchip Technology Consulting (Shanghai)
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Shenzhen 518033, China
Tel: 86-755-82901380 Fax: 86-755-8295-1393

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Rm. B505A, Fullhope Plaza,
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Qingdao 266071, China
Tel: 86-532-5027355 Fax: 86-532-5027205

India

Microchip Technology Inc.
India Liaison Office
Marketing Support Division
Divyasree Chambers
1 Floor, Wing A (A3/A4)
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Bangalore, 560 025, India
Tel: 91-80-2290061 Fax: 91-80-2290062

Japan

Microchip Technology Japan K.K.
Benex S-1 6F
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Samsung-Dong, Kangnam-Ku
Seoul, Korea 135-882
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Singapore

Microchip Technology Singapore Pte Ltd.
200 Middle Road
#07-02 Prime Centre
Singapore, 188980
Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan

Microchip Technology (Barbados) Inc.,
Taiwan Branch
11F-3, No. 207
Tung Hua North Road
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Tel: 886-2-2717-7175 Fax: 886-2-2545-0139

EUROPE

Austria

Microchip Technology Austria GmbH
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Austria
Tel: 43-7242-2244-399
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Germany

Microchip Technology GmbH
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D-85737 Ismaning, Germany
Tel: 49-89-627-144-0
Fax: 49-89-627-144-44

Italy

Microchip Technology SRL
Via Quasimodo, 12
20025 Legnano (MI)
Milan, Italy
Tel: 39-0331-742611 Fax: 39-0331-466781

United Kingdom

Microchip Ltd.
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Wokingham
Berkshire, England RG41 5TU
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